MOS FET Relays

G3VM-81G1

New Relay Incorporating a MOS FET Optically Coupled with an Infrared LED Has a 4-pin SOP Package and 80-V Load Voltage

- Continuous load current of 350 mA.
- Dielectric strength of 1,500 Vrms between I/O.

■ Application Examples

- Broadband systems
- Measurement devices
- · Data loggers
- · Amusement machines



Note: The actual product is marked differently from the image shown here.

■ List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	80 VAC	G3VM-81G1	100	
	terminals		G3VM-81G1(TR)		2,500

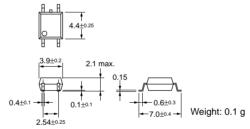
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

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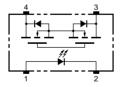


Note: The actual product is marked differently from the image shown here.



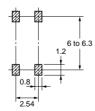
■ Terminal Arrangement/Internal Connections (Top View)

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■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

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Note:

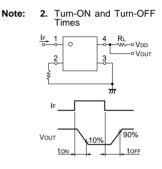
■ Absolute Maximum Ratings (Ta = 25°C)

Item		Symbol	Rating	Unit	Measurement Conditions	
Input	LED forward current	I _F	50	mA		
	Repetitive peak LED forward current		1	Α	100 μs pulses, 100 pps	
	LED forward current reduction rate	Δ I _F /°C	-0.5	mA/°C	Ta ≥ 25°C	
	LED reverse voltage	V_R	5	V		
	Connection temperature	Tj	125	°C		
Output	Output dielectric strength	V _{OFF}	80	V		
	Continuous load current	I _O	350	mA		
	ON current reduction rate	Δ I _{ON} /°C	-3.5	mA/°C	Ta ≥ 25°C	
	Connection temperature	Tj	125	°C		
	ic strength between input and See note 1.)	V _{I-O}	1,500	Vrms	AC for 1 min	
Operati	Operating temperature		-40 to +85	°C	With no icing or condensation	
Storage	Storage temperature		-55 to +125	°C	With no icing or condensation	
Solderin	Soldering temperature (10 s)		260	°C	10 s	

The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

■ Electrical Characteristics (Ta = 25°C)

ltem		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage	V_{F}	1.0	1.15	1.3	V	I _F = 10 mA	
	Reverse current	I _R			10	μА	V _R = 5 V	
	Capacity between terminals	C _T		15		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I _{FT}		1.0	4.0	mA	I _O = 350 mA	
Output	Maximum resistance with output ON	R _{ON}		1.0	1.2	Ω	I _F = 5 mA, I _O = 350 mA	
	Current leakage when the relay is open	I _{LEAK}		0.2	1.0	nA	V _{OFF} = 30 V, Ta = 50°C	
Capacity between I/O terminals		C _{I-O}		0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		R _{I-O}	1,000			ΜΩ	V_{I-O} = 500 VDC, RoH \leq 60%	
Turn-ON time		tON		0.3	0.5	ms	I_F = 5 mA, R_L = 200 Ω , V_{DD} = 20 V (See note 2.)	
Turn-OFF time		tOFF		0.3	0.5	ms		



■ Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	V_{DD}			64	V
Operating LED forward current	I _F	5		30	mA
Continuous load current	Io			350	mA
Operating temperature	Ta	25		60	°C

■ Engineering Data

Load Current vs. Ambient Temperature G3VM-81G1

■ Safety Precautions

Refer to page 6 for precautions common to all G3VM models.